

# 74LVC1G66

## Bilateral switch

Rev. 9 — 15 January 2015

Product data sheet

## 1. General description

The 74LVC1G66 provides one single pole, single-throw analog switch function. It has two input/output terminals (Y and Z) and an active HIGH enable input pin (E). When E is LOW, the analog switch is turned off.

Schmitt-trigger action at the enable input makes the circuit tolerant of slower input rise and fall times across the entire  $V_{CC}$  range from 1.65 V to 5.5 V.

## 2. Features and benefits

- Wide supply voltage range from 1.65 V to 5.5 V
- Very low ON resistance:
  - ◆ 7.5  $\Omega$  (typical) at  $V_{CC} = 2.7$  V
  - ◆ 6.5  $\Omega$  (typical) at  $V_{CC} = 3.3$  V
  - ◆ 6  $\Omega$  (typical) at  $V_{CC} = 5$  V
- Switch current capability of 32 mA
- High noise immunity
- CMOS low power consumption
- TTL interface compatibility at 3.3 V
- Latch-up performance meets requirements of JESD78 Class I
- ESD protection:
  - ◆ HBM JESD22-A114F exceeds 2000 V
  - ◆ MM JESD22-A115-A exceeds 200 V
- Enable input accepts voltages up to 5.5 V
- Multiple package options
- Specified from  $-40$  °C to  $+85$  °C and  $-40$  °C to  $+125$  °C

## 3. Ordering information

Table 1. Ordering information

| Type number | Package               |        |                                                                                                         |          |
|-------------|-----------------------|--------|---------------------------------------------------------------------------------------------------------|----------|
|             | Temperature range     | Name   | Description                                                                                             | Version  |
| 74LVC1G66GW | $-40$ °C to $+125$ °C | TSSOP5 | plastic thin shrink small outline package; 5 leads; body width 1.25 mm                                  | SOT353-1 |
| 74LVC1G66GV | $-40$ °C to $+125$ °C | SC-74A | plastic surface-mounted package; 5 leads                                                                | SOT753   |
| 74LVC1G66GM | $-40$ °C to $+125$ °C | XSON6  | plastic extremely thin small outline package; no leads; 6 terminals; body $1 \times 1.45 \times 0.5$ mm | SOT886   |



Table 1. Ordering information ...continued

| Type number | Package           |       |                                                                                          |         |
|-------------|-------------------|-------|------------------------------------------------------------------------------------------|---------|
|             | Temperature range | Name  | Description                                                                              | Version |
| 74LVC1G66GF | −40 °C to +125 °C | XSON6 | plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1 × 0.5 mm | SOT891  |
| 74LVC1G66GN | −40 °C to +125 °C | XSON6 | extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm    | SOT1115 |
| 74LVC1G66GS | −40 °C to +125 °C | XSON6 | extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm    | SOT1202 |

4. Marking

Table 2. Marking

| Type number | Marking code <sup>[1]</sup> |
|-------------|-----------------------------|
| 74LVC1G66GW | VL                          |
| 74LVC1G66GV | V66                         |
| 74LVC1G66GM | VL                          |
| 74LVC1G66GF | VL                          |
| 74LVC1G66GN | VL                          |
| 74LVC1G66GS | VL                          |

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram

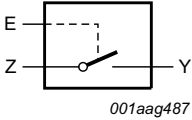


Fig 1. Logic symbol

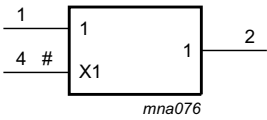


Fig 2. IEC logic symbol

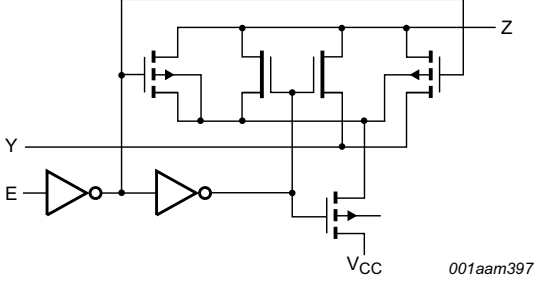
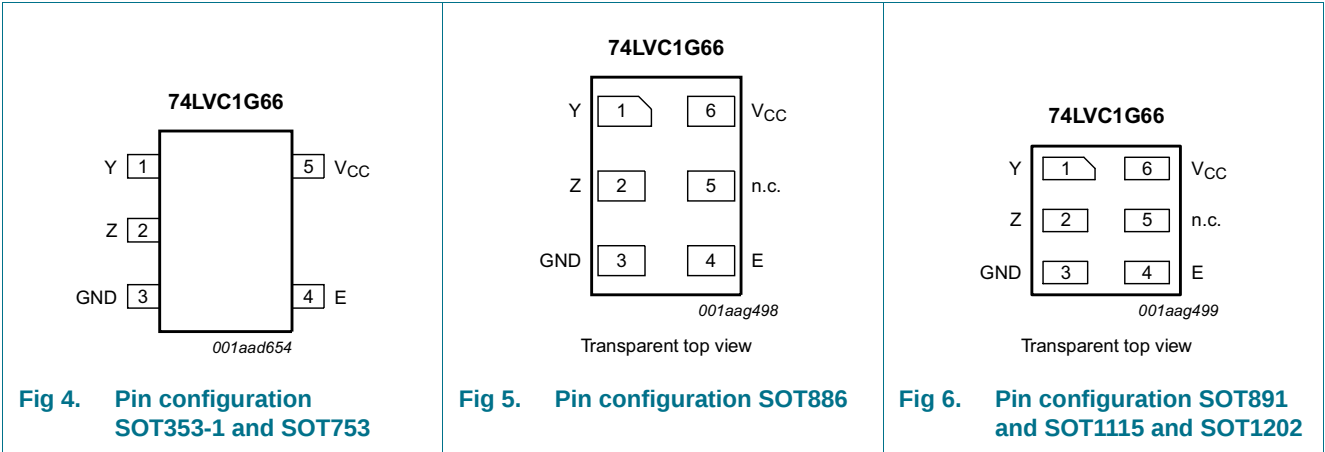


Fig 3. Logic diagram

6. Pinning information

6.1 Pinning



6.2 Pin description

Table 3. Pin description

| Symbol          | Pin              |                                     | Description                 |
|-----------------|------------------|-------------------------------------|-----------------------------|
|                 | SOT353-1, SOT753 | SOT886, SOT891, SOT1115 and SOT1202 |                             |
| Y               | 1                | 1                                   | independent input or output |
| Z               | 2                | 2                                   | independent output or input |
| GND             | 3                | 3                                   | ground (0 V)                |
| E               | 4                | 4                                   | enable input (active HIGH)  |
| n.c.            | -                | 5                                   | not connected               |
| V <sub>CC</sub> | 5                | 6                                   | supply voltage              |

7. Functional description

Table 4. Function table<sup>[1]</sup>

| Input E | Switch    |
|---------|-----------|
| L       | OFF-state |
| H       | ON-state  |

[1] H = HIGH voltage level; L = LOW voltage level

## 8. Limiting values

**Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol    | Parameter               | Conditions                                                   | Min  | Max            | Unit |
|-----------|-------------------------|--------------------------------------------------------------|------|----------------|------|
| $V_{CC}$  | supply voltage          |                                                              | -0.5 | +6.5           | V    |
| $V_I$     | input voltage           | [1]                                                          | -0.5 | +6.5           | V    |
| $I_{IK}$  | input clamping current  | $V_I < -0.5\text{ V}$ or $V_I > V_{CC} + 0.5\text{ V}$       | -50  | -              | mA   |
| $I_{SK}$  | switch clamping current | $V_I < -0.5\text{ V}$ or $V_I > V_{CC} + 0.5\text{ V}$       | -    | ±50            | mA   |
| $V_{SW}$  | switch voltage          | enable and disable mode [2]                                  | -0.5 | $V_{CC} + 0.5$ | V    |
| $I_{SW}$  | switch current          | $V_{SW} > -0.5\text{ V}$ or $V_{SW} < V_{CC} + 0.5\text{ V}$ | -    | ±50            | mA   |
| $I_{CC}$  | supply current          |                                                              | -    | 100            | mA   |
| $I_{GND}$ | ground current          |                                                              | -100 | -              | mA   |
| $T_{stg}$ | storage temperature     |                                                              | -65  | +150           | °C   |
| $P_{tot}$ | total power dissipation | $T_{amb} = -40\text{ °C}$ to $+125\text{ °C}$ [3]            | -    | 250            | mW   |

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed.

[3] For TSSOP5 and SC-74A packages: above 87.5 °C the value of  $P_{tot}$  derates linearly with 4.0 mW/K.  
For XSON6 packages: above 118 °C the value of  $P_{tot}$  derates linearly with 7.8 mW/K.

## 9. Recommended operating conditions

**Table 6. Recommended operating conditions**

| Symbol              | Parameter                           | Conditions                                     | Min  | Typ | Max      | Unit |
|---------------------|-------------------------------------|------------------------------------------------|------|-----|----------|------|
| $V_{CC}$            | supply voltage                      |                                                | 1.65 | -   | 5.5      | V    |
| $V_I$               | input voltage                       |                                                | 0    | -   | 5.5      | V    |
| $V_{SW}$            | switch voltage                      | [1]                                            | 0    | -   | $V_{CC}$ | V    |
| $T_{amb}$           | ambient temperature                 |                                                | -40  | -   | +125     | °C   |
| $\Delta t/\Delta V$ | input transition rise and fall rate | $V_{CC} = 1.65\text{ V}$ to $2.7\text{ V}$ [2] | -    | -   | 20       | ns/V |
|                     |                                     | $V_{CC} = 2.7\text{ V}$ to $5.5\text{ V}$ [2]  | -    | -   | 10       | ns/V |

[1] To avoid sinking GND current from terminal Z when switch current flows in terminal Y, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no GND current will flow from terminal Y. In this case, there is no limit for the voltage drop across the switch.

[2] Applies to control signal levels.

## 10. Static characteristics

**Table 7. Static characteristics**

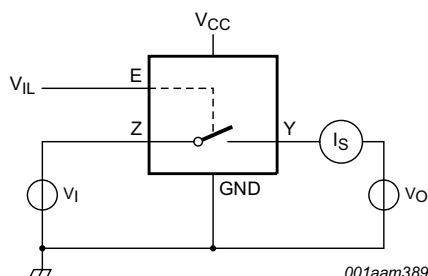
At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol              | Parameter                 | Conditions                                                                                                                         | –40 °C to +85 °C    |                    |                     | –40 °C to +125 °C   |                     | Unit |
|---------------------|---------------------------|------------------------------------------------------------------------------------------------------------------------------------|---------------------|--------------------|---------------------|---------------------|---------------------|------|
|                     |                           |                                                                                                                                    | Min                 | Typ <sup>[1]</sup> | Max                 | Min                 | Max                 |      |
| V <sub>IH</sub>     | HIGH-level input voltage  | V <sub>CC</sub> = 1.65 V to 1.95 V                                                                                                 | 0.65V <sub>CC</sub> | -                  | -                   | 0.65V <sub>CC</sub> | -                   | V    |
|                     |                           | V <sub>CC</sub> = 2.3 V to 2.7 V                                                                                                   | 1.7                 | -                  | -                   | 1.7                 | -                   | V    |
|                     |                           | V <sub>CC</sub> = 2.7 V to 3.6 V                                                                                                   | 2.0                 | -                  | -                   | 2.0                 | -                   | V    |
|                     |                           | V <sub>CC</sub> = 4.5 V to 5.5 V                                                                                                   | 0.7V <sub>CC</sub>  | -                  | -                   | 0.7V <sub>CC</sub>  | -                   | V    |
| V <sub>IL</sub>     | LOW-level input voltage   | V <sub>CC</sub> = 1.65 V to 1.95 V                                                                                                 | -                   | -                  | 0.35V <sub>CC</sub> | -                   | 0.35V <sub>CC</sub> | V    |
|                     |                           | V <sub>CC</sub> = 2.3 V to 2.7 V                                                                                                   | -                   | -                  | 0.7                 | -                   | 0.7                 | V    |
|                     |                           | V <sub>CC</sub> = 2.7 V to 3.6 V                                                                                                   | -                   | -                  | 0.8                 | -                   | 0.8                 | V    |
|                     |                           | V <sub>CC</sub> = 4.5 V to 5.5 V                                                                                                   | -                   | -                  | 0.3V <sub>CC</sub>  | -                   | 0.3V <sub>CC</sub>  | V    |
| I <sub>I</sub>      | input leakage current     | pin E; V <sub>I</sub> = 5.5 V or GND; V <sub>CC</sub> = 0 V to 5.5 V <sup>[2]</sup>                                                | -                   | ±0.1               | ±5                  | -                   | ±100                | μA   |
| I <sub>S(OFF)</sub> | OFF-state leakage current | V <sub>CC</sub> = 5.5 V; see <a href="#">Figure 7</a> <sup>[2]</sup>                                                               | -                   | ±0.1               | ±5                  | -                   | ±200                | μA   |
| I <sub>S(ON)</sub>  | ON-state leakage current  | V <sub>CC</sub> = 5.5 V; see <a href="#">Figure 8</a> <sup>[2]</sup>                                                               | -                   | ±0.1               | ±5                  | -                   | ±200                | μA   |
| I <sub>CC</sub>     | supply current            | V <sub>I</sub> = 5.5 V or GND; V <sub>SW</sub> = GND or V <sub>CC</sub> ; V <sub>CC</sub> = 1.65 V to 5.5 V <sup>[2]</sup>         | -                   | 0.1                | 10                  | -                   | 200                 | μA   |
| ΔI <sub>CC</sub>    | additional supply current | pin E; V <sub>I</sub> = V <sub>CC</sub> – 0.6 V; V <sub>SW</sub> = GND or V <sub>CC</sub> ; V <sub>CC</sub> = 5.5 V <sup>[2]</sup> | -                   | 5                  | 500                 | -                   | 5000                | μA   |
| C <sub>I</sub>      | input capacitance         |                                                                                                                                    | -                   | 2.0                | -                   | -                   | -                   | pF   |
| C <sub>S(OFF)</sub> | OFF-state capacitance     |                                                                                                                                    | -                   | 6.5                | -                   | -                   | -                   | pF   |
| C <sub>S(ON)</sub>  | ON-state capacitance      |                                                                                                                                    | -                   | 11                 | -                   | -                   | -                   | pF   |

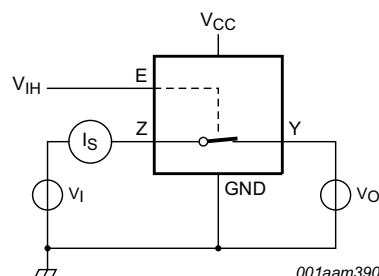
[1] All typical values are measured at T<sub>amb</sub> = 25 °C.

[2] These typical values are measured at V<sub>CC</sub> = 3.3 V.

## 10.1 Test circuits


$$V_I = V_{CC} \text{ or GND and } V_O = \text{GND or } V_{CC}.$$

**Fig 7. Test circuit for measuring OFF-state leakage current**



$V_I = V_{CC}$  or GND and  $V_O =$  open circuit.

**Fig 8. Test circuit for measuring ON-state leakage current**

## 10.2 ON resistance

### Table 8. ON resistance

At recommended operating conditions; voltages are referenced to GND (ground 0 V); for graphs see [Figure 10](#) to [Figure 15](#).

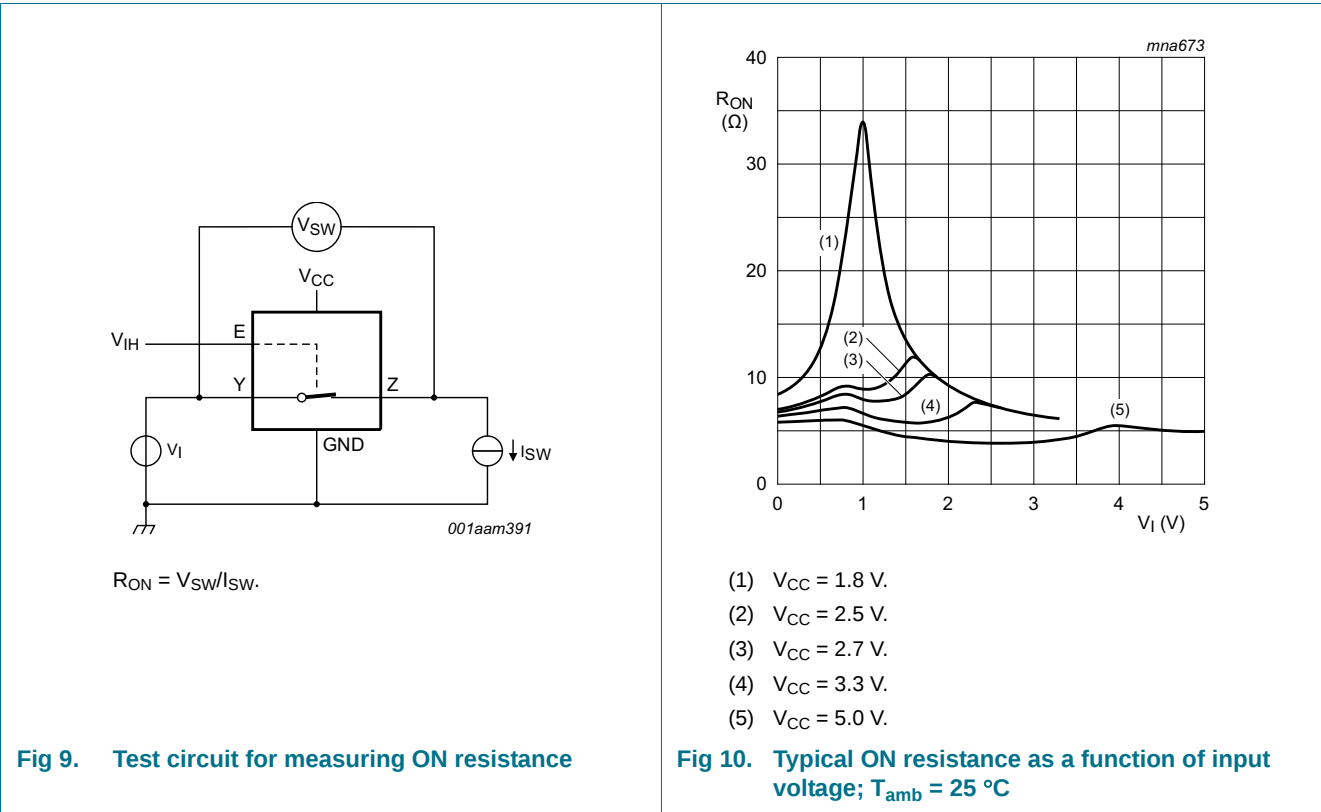
| Symbol                | Parameter            | Conditions                                                             | -40 °C to +85 °C |                    |     | -40 °C to +125 °C |     | Unit |
|-----------------------|----------------------|------------------------------------------------------------------------|------------------|--------------------|-----|-------------------|-----|------|
|                       |                      |                                                                        | Min              | Typ <sup>[1]</sup> | Max | Min               | Max |      |
| R <sub>ON(peak)</sub> | ON resistance (peak) | V <sub>I</sub> = GND to V <sub>CC</sub> ; see <a href="#">Figure 9</a> |                  |                    |     |                   |     |      |
|                       |                      | I <sub>SW</sub> = 4 mA;<br>V <sub>CC</sub> = 1.65 V to 1.95 V          | -                | 34.0               | 130 | -                 | 195 | Ω    |
|                       |                      | I <sub>SW</sub> = 8 mA; V <sub>CC</sub> = 2.3 V to 2.7 V               | -                | 12.0               | 30  | -                 | 45  | Ω    |
|                       |                      | I <sub>SW</sub> = 12 mA; V <sub>CC</sub> = 2.7 V                       | -                | 10.4               | 25  | -                 | 38  | Ω    |
|                       |                      | I <sub>SW</sub> = 24 mA; V <sub>CC</sub> = 3.0 V to 3.6 V              | -                | 7.8                | 20  | -                 | 30  | Ω    |
|                       |                      | I <sub>SW</sub> = 32 mA; V <sub>CC</sub> = 4.5 V to 5.5 V              | -                | 6.2                | 15  | -                 | 23  | Ω    |
| R <sub>ON(rail)</sub> | ON resistance (rail) | V <sub>I</sub> = GND; see <a href="#">Figure 9</a>                     |                  |                    |     |                   |     |      |
|                       |                      | I <sub>SW</sub> = 4 mA;<br>V <sub>CC</sub> = 1.65 V to 1.95 V          | -                | 8.2                | 18  | -                 | 27  | Ω    |
|                       |                      | I <sub>SW</sub> = 8 mA; V <sub>CC</sub> = 2.3 V to 2.7 V               | -                | 7.1                | 16  | -                 | 24  | Ω    |
|                       |                      | I <sub>SW</sub> = 12 mA; V <sub>CC</sub> = 2.7 V                       | -                | 6.9                | 14  | -                 | 21  | Ω    |
|                       |                      | I <sub>SW</sub> = 24 mA; V <sub>CC</sub> = 3.0 V to 3.6 V              | -                | 6.5                | 12  | -                 | 18  | Ω    |
|                       |                      | I <sub>SW</sub> = 32 mA; V <sub>CC</sub> = 4.5 V to 5.5 V              | -                | 5.8                | 10  | -                 | 15  | Ω    |
|                       |                      | V <sub>I</sub> = V <sub>CC</sub> ; see <a href="#">Figure 9</a>        |                  |                    |     |                   |     |      |
|                       |                      | I <sub>SW</sub> = 4 mA;<br>V <sub>CC</sub> = 1.65 V to 1.95 V          | -                | 10.4               | 30  | -                 | 45  | Ω    |
|                       |                      | I <sub>SW</sub> = 8 mA; V <sub>CC</sub> = 2.3 V to 2.7 V               | -                | 7.6                | 20  | -                 | 30  | Ω    |
|                       |                      | I <sub>SW</sub> = 12 mA; V <sub>CC</sub> = 2.7 V                       | -                | 7.0                | 18  | -                 | 27  | Ω    |
|                       |                      | I <sub>SW</sub> = 24 mA; V <sub>CC</sub> = 3.0 V to 3.6 V              | -                | 6.1                | 15  | -                 | 23  | Ω    |
|                       |                      | I <sub>SW</sub> = 32 mA; V <sub>CC</sub> = 4.5 V to 5.5 V              | -                | 4.9                | 10  | -                 | 15  | Ω    |

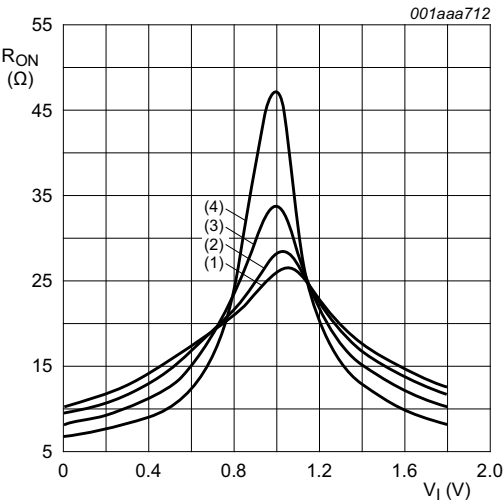
**Table 8. ON resistance ...continued**  
 At recommended operating conditions; voltages are referenced to GND (ground 0 V); for graphs see [Figure 10](#) to [Figure 15](#).

| Symbol                | Parameter                | Conditions                                                 | −40 °C to +85 °C |                    |     | −40 °C to +125 °C |     | Unit |
|-----------------------|--------------------------|------------------------------------------------------------|------------------|--------------------|-----|-------------------|-----|------|
|                       |                          |                                                            | Min              | Typ <sup>[1]</sup> | Max | Min               | Max |      |
| R <sub>ON(flat)</sub> | ON resistance (flatness) | V <sub>I</sub> = GND to V <sub>CC</sub> <sup>[2]</sup>     |                  |                    |     |                   |     |      |
|                       |                          | I <sub>SW</sub> = 4 mA; V <sub>CC</sub> = 1.65 V to 1.95 V | -                | 26.0               | -   | -                 | -   | Ω    |
|                       |                          | I <sub>SW</sub> = 8 mA; V <sub>CC</sub> = 2.3 V to 2.7 V   | -                | 5.0                | -   | -                 | -   | Ω    |
|                       |                          | I <sub>SW</sub> = 12 mA; V <sub>CC</sub> = 2.7 V           | -                | 3.5                | -   | -                 | -   | Ω    |
|                       |                          | I <sub>SW</sub> = 24 mA; V <sub>CC</sub> = 3.0 V to 3.6 V  | -                | 2.0                | -   | -                 | -   | Ω    |
|                       |                          | I <sub>SW</sub> = 32 mA; V <sub>CC</sub> = 4.5 V to 5.5 V  | -                | 1.5                | -   | -                 | -   | Ω    |

- [1] Typical values are measured at T<sub>amb</sub> = 25 °C and nominal V<sub>CC</sub>.
- [2] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical V<sub>CC</sub> and temperature.

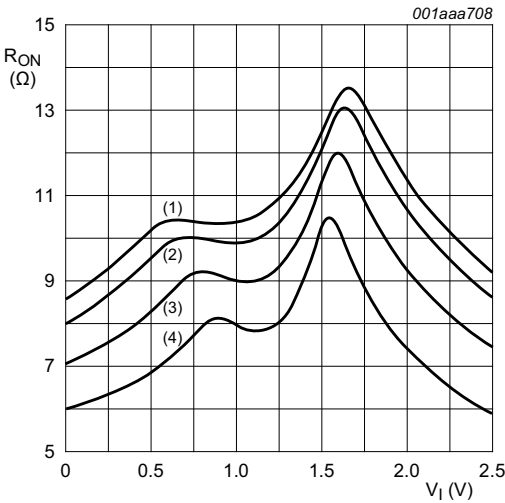
10.3 ON resistance test circuit and graphs





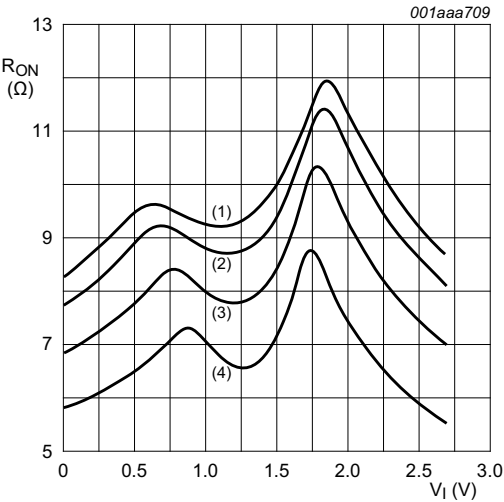
- (1)  $T_{amb} = 125$  °C.
- (2)  $T_{amb} = 85$  °C.
- (3)  $T_{amb} = 25$  °C.
- (4)  $T_{amb} = -40$  °C.

Fig 11. ON resistance as a function of input voltage;  
 $V_{CC} = 1.8$  V



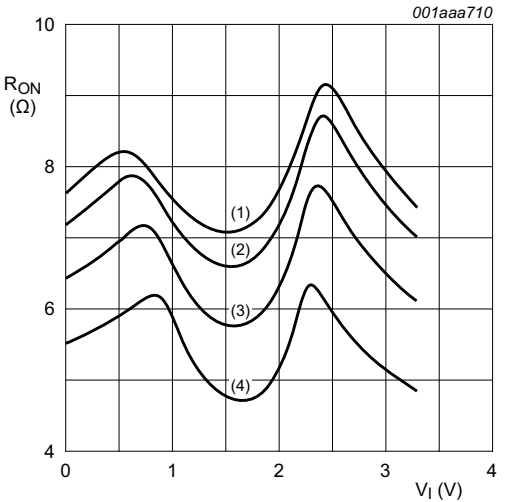
- (1)  $T_{amb} = 125$  °C.
- (2)  $T_{amb} = 85$  °C.
- (3)  $T_{amb} = 25$  °C.
- (4)  $T_{amb} = -40$  °C.

Fig 12. ON resistance as a function of input voltage;  
 $V_{CC} = 2.5$  V



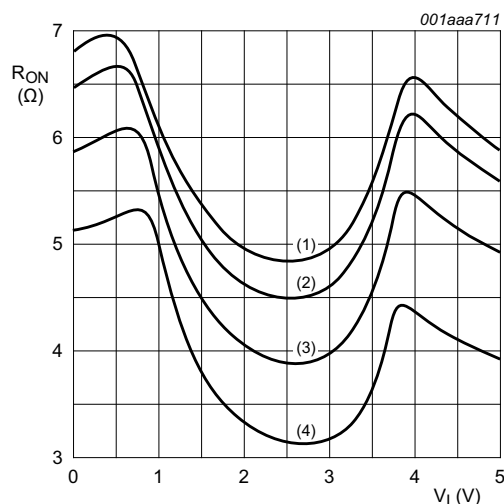
- (1)  $T_{amb} = 125$  °C.
- (2)  $T_{amb} = 85$  °C.
- (3)  $T_{amb} = 25$  °C.
- (4)  $T_{amb} = -40$  °C.

Fig 13. ON resistance as a function of input voltage;  
 $V_{CC} = 2.7$  V



- (1)  $T_{amb} = 125$  °C.
- (2)  $T_{amb} = 85$  °C.
- (3)  $T_{amb} = 25$  °C.
- (4)  $T_{amb} = -40$  °C.

Fig 14. ON resistance as a function of input voltage;  
 $V_{CC} = 3.3$  V



- (1)  $T_{amb} = 125\text{ }^{\circ}\text{C}$ .  
 (2)  $T_{amb} = 85\text{ }^{\circ}\text{C}$ .  
 (3)  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .  
 (4)  $T_{amb} = -40\text{ }^{\circ}\text{C}$ .

Fig 15. ON resistance as a function of input voltage;  $V_{CC} = 5.0\text{ V}$

## 11. Dynamic characteristics

**Table 9. Dynamic characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 18](#).

| Symbol   | Parameter         | Conditions                                                        | -40 °C to +85 °C |                    |     | -40 °C to +125 °C |      | Unit |
|----------|-------------------|-------------------------------------------------------------------|------------------|--------------------|-----|-------------------|------|------|
|          |                   |                                                                   | Min              | Typ <sup>[1]</sup> | Max | Min               | Max  |      |
| $t_{pd}$ | propagation delay | Y to Z or Z to Y; see <a href="#">Figure 16</a> <sup>[2][3]</sup> |                  |                    |     |                   |      |      |
|          |                   | $V_{CC} = 1.65\text{ V to }1.95\text{ V}$                         | -                | 0.8                | 2.0 | -                 | 3.0  | ns   |
|          |                   | $V_{CC} = 2.3\text{ V to }2.7\text{ V}$                           | -                | 0.4                | 1.2 | -                 | 2.0  | ns   |
|          |                   | $V_{CC} = 2.7\text{ V}$                                           | -                | 0.4                | 1.0 | -                 | 1.5  | ns   |
|          |                   | $V_{CC} = 3.0\text{ V to }3.6\text{ V}$                           | -                | 0.3                | 0.8 | -                 | 1.5  | ns   |
|          |                   | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$                           | -                | 0.2                | 0.6 | -                 | 1.0  | ns   |
| $t_{en}$ | enable time       | E to Y or Z; see <a href="#">Figure 17</a> <sup>[4]</sup>         |                  |                    |     |                   |      |      |
|          |                   | $V_{CC} = 1.65\text{ V to }1.95\text{ V}$                         | 1.0              | 5.3                | 12  | 1.0               | 15.5 | ns   |
|          |                   | $V_{CC} = 2.3\text{ V to }2.7\text{ V}$                           | 1.0              | 3.0                | 6.5 | 1.0               | 8.5  | ns   |
|          |                   | $V_{CC} = 2.7\text{ V}$                                           | 1.0              | 2.6                | 6.0 | 1.0               | 8.0  | ns   |
|          |                   | $V_{CC} = 3.0\text{ V to }3.6\text{ V}$                           | 1.0              | 2.5                | 5.0 | 1.0               | 6.5  | ns   |
|          |                   | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$                           | 1.0              | 1.9                | 4.2 | 1.0               | 5.5  | ns   |

**Table 9. Dynamic characteristics ...continued**At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 18](#).

| Symbol           | Parameter                     | Conditions                                                                                              | -40 °C to +85 °C |                    |     | -40 °C to +125 °C |     | Unit |
|------------------|-------------------------------|---------------------------------------------------------------------------------------------------------|------------------|--------------------|-----|-------------------|-----|------|
|                  |                               |                                                                                                         | Min              | Typ <sup>[1]</sup> | Max | Min               | Max |      |
| t <sub>dis</sub> | disable time                  | E to Y or Z; see <a href="#">Figure 17</a> <sup>[5]</sup>                                               |                  |                    |     |                   |     |      |
|                  |                               | V <sub>CC</sub> = 1.65 V to 1.95 V                                                                      | 1.0              | 4.2                | 10  | 1.0               | 13  | ns   |
|                  |                               | V <sub>CC</sub> = 2.3 V to 2.7 V                                                                        | 1.0              | 2.4                | 6.9 | 1.0               | 9.0 | ns   |
|                  |                               | V <sub>CC</sub> = 2.7 V                                                                                 | 1.0              | 3.6                | 7.5 | 1.0               | 9.5 | ns   |
|                  |                               | V <sub>CC</sub> = 3.0 V to 3.6 V                                                                        | 1.0              | 3.4                | 6.5 | 1.0               | 8.5 | ns   |
|                  |                               | V <sub>CC</sub> = 4.5 V to 5.5 V                                                                        | 1.0              | 2.5                | 5.0 | 1.0               | 6.5 | ns   |
| C <sub>PD</sub>  | power dissipation capacitance | C <sub>L</sub> = 50 pF; f <sub>i</sub> = 10 MHz; V <sub>I</sub> = GND to V <sub>CC</sub> <sup>[6]</sup> |                  |                    |     |                   |     |      |
|                  |                               | V <sub>CC</sub> = 2.5 V                                                                                 | -                | 9.8                | -   | -                 | -   | pF   |
|                  |                               | V <sub>CC</sub> = 3.3 V                                                                                 | -                | 12.0               | -   | -                 | -   | pF   |
|                  |                               | V <sub>CC</sub> = 5.0 V                                                                                 | -                | 17.3               | -   | -                 | -   | pF   |

[1] Typical values are measured at T<sub>amb</sub> = 25 °C and nominal V<sub>CC</sub>.[2] t<sub>pd</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub>.

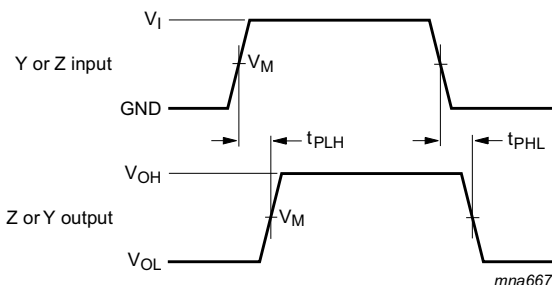
[3] propagation delay is the calculated RC time constant of the typical ON resistance of the switch and the specified capacitance when driven by an ideal voltage source (zero output impedance).

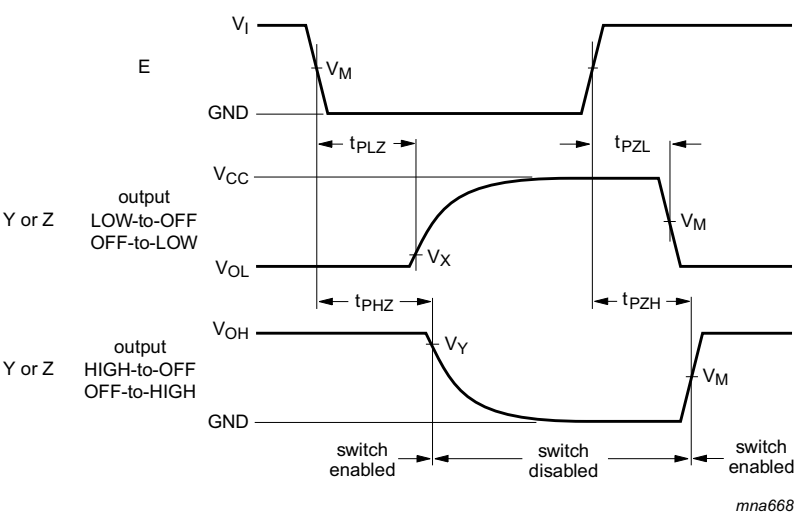
[4] t<sub>en</sub> is the same as t<sub>PZH</sub> and t<sub>PZL</sub>.[5] t<sub>dis</sub> is the same as t<sub>PLZ</sub> and t<sub>PHZ</sub>.[6] C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in μW).
$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum \{(C_L + C_{S(ON)}) \times V_{CC}^2 \times f_o\}$$
 where:
f<sub>i</sub> = input frequency in MHz;f<sub>o</sub> = output frequency in MHz;C<sub>L</sub> = output load capacitance in pF;C<sub>S(ON)</sub> = maximum ON-state switch capacitance in pF;V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

Σ{(C<sub>L</sub> + C<sub>S(ON)</sub>) × V<sub>CC</sub><sup>2</sup> × f<sub>o</sub>} = sum of the outputs.

## 11.1 Waveforms and test circuit

Measurement points are given in [Table 10](#).Logic levels: V<sub>OL</sub> and V<sub>OH</sub> are typical output voltage levels that occur with the output load.**Fig 16. Input (Y or Z) to output (Z or Y) propagation delays**

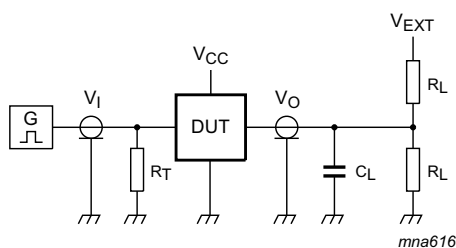


Measurement points are given in [Table 10](#).  
Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

Fig 17. Enable and disable times

Table 10. Measurement points

| Supply voltage   | Input       | Output      |                          |                          |
|------------------|-------------|-------------|--------------------------|--------------------------|
| $V_{CC}$         | $V_M$       | $V_M$       | $V_X$                    | $V_Y$                    |
| 1.65 V to 1.95 V | $0.5V_{CC}$ | $0.5V_{CC}$ | $V_{OL} + 0.15\text{ V}$ | $V_{OH} - 0.15\text{ V}$ |
| 2.3 V to 2.7 V   | $0.5V_{CC}$ | $0.5V_{CC}$ | $V_{OL} + 0.15\text{ V}$ | $V_{OH} - 0.15\text{ V}$ |
| 2.7 V            | 1.5 V       | 1.5 V       | $V_{OL} + 0.3\text{ V}$  | $V_{OH} - 0.3\text{ V}$  |
| 3.0 V to 3.6 V   | 1.5 V       | 1.5 V       | $V_{OL} + 0.3\text{ V}$  | $V_{OH} - 0.3\text{ V}$  |
| 4.5 V to 5.5 V   | $0.5V_{CC}$ | $0.5V_{CC}$ | $V_{OL} + 0.3\text{ V}$  | $V_{OH} - 0.3\text{ V}$  |



Test data is given in [Table 11](#).

Definitions for test circuit:

$R_T$  = Termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.

$C_L$  = Load capacitance including jig and probe capacitance.

$R_L$  = Load resistance.

$V_{EXT}$  = External voltage for measuring switching times.

**Fig 18. Test circuit for measuring switching times**

**Table 11. Test data**

| Supply voltage   | Input    |               | Load  |              | $V_{EXT}$          |                    |                    |
|------------------|----------|---------------|-------|--------------|--------------------|--------------------|--------------------|
| $V_{CC}$         | $V_I$    | $t_r, t_f$    | $C_L$ | $R_L$        | $t_{PLH}, t_{PHL}$ | $t_{PZH}, t_{PHZ}$ | $t_{PZL}, t_{PLZ}$ |
| 1.65 V to 1.95 V | $V_{CC}$ | $\leq 2.0$ ns | 30 pF | 1 k $\Omega$ | open               | GND                | $2V_{CC}$          |
| 2.3 V to 2.7 V   | $V_{CC}$ | $\leq 2.0$ ns | 30 pF | 500 $\Omega$ | open               | GND                | $2V_{CC}$          |
| 2.7 V            | 2.7 V    | $\leq 2.5$ ns | 50 pF | 500 $\Omega$ | open               | GND                | 6 V                |
| 3.0 V to 3.6 V   | 2.7 V    | $\leq 2.5$ ns | 50 pF | 500 $\Omega$ | open               | GND                | 6 V                |
| 4.5 V to 5.5 V   | $V_{CC}$ | $\leq 2.5$ ns | 50 pF | 500 $\Omega$ | open               | GND                | $2V_{CC}$          |

## 11.2 Additional dynamic characteristics

**Table 12. Additional dynamic characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V);  $T_{amb} = 25$  °C.

| Symbol | Parameter                 | Conditions                                                                              | Min | Typ   | Max | Unit |
|--------|---------------------------|-----------------------------------------------------------------------------------------|-----|-------|-----|------|
| THD    | total harmonic distortion | $R_L = 10$ k $\Omega$ ; $C_L = 50$ pF; $f_i = 1$ kHz;<br>see <a href="#">Figure 19</a>  |     |       |     |      |
|        |                           | $V_{CC} = 1.65$ V                                                                       | -   | 0.032 | -   | %    |
|        |                           | $V_{CC} = 2.3$ V                                                                        | -   | 0.008 | -   | %    |
|        |                           | $V_{CC} = 3.0$ V                                                                        | -   | 0.006 | -   | %    |
|        |                           | $V_{CC} = 4.5$ V                                                                        | -   | 0.001 | -   | %    |
|        |                           | $R_L = 10$ k $\Omega$ ; $C_L = 50$ pF; $f_i = 10$ kHz;<br>see <a href="#">Figure 19</a> |     |       |     |      |
|        |                           | $V_{CC} = 1.65$ V                                                                       | -   | 0.068 | -   | %    |
|        |                           | $V_{CC} = 2.3$ V                                                                        | -   | 0.009 | -   | %    |
|        |                           | $V_{CC} = 3.0$ V                                                                        | -   | 0.008 | -   | %    |
|        |                           | $V_{CC} = 4.5$ V                                                                        | -   | 0.006 | -   | %    |

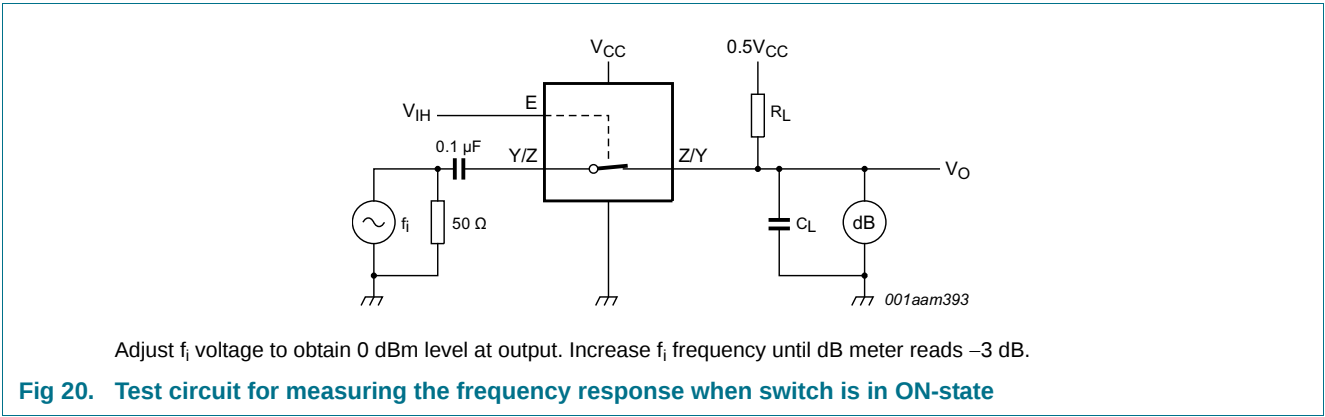
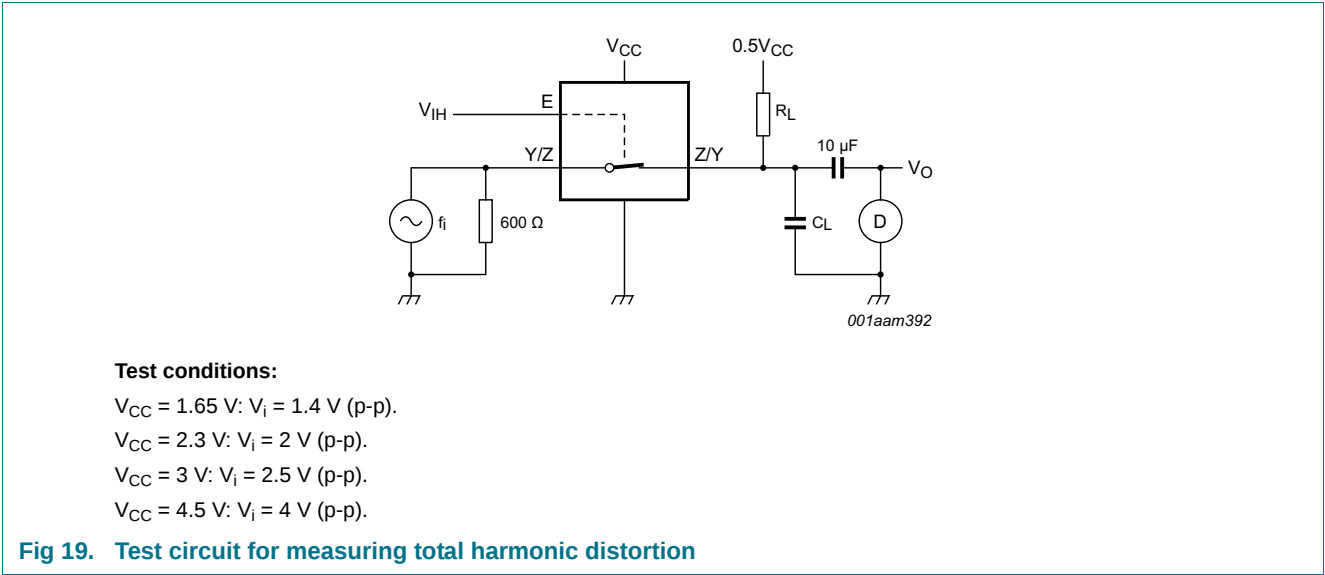
**Table 12. Additional dynamic characteristics ...continued**At recommended operating conditions; voltages are referenced to GND (ground = 0 V);  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .

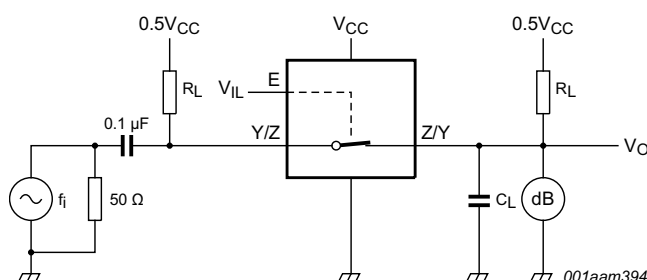
| Symbol         | Parameter                | Conditions                                                                                                                                                                  | Min | Typ   | Max | Unit |
|----------------|--------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----|-------|-----|------|
| $f_{(-3dB)}$   | -3 dB frequency response | $R_L = 600\text{ }\Omega$ ; $C_L = 50\text{ pF}$ ;<br>see <a href="#">Figure 20</a>                                                                                         |     |       |     |      |
|                |                          | $V_{CC} = 1.65\text{ V}$                                                                                                                                                    | -   | 135   | -   | MHz  |
|                |                          | $V_{CC} = 2.3\text{ V}$                                                                                                                                                     | -   | 145   | -   | MHz  |
|                |                          | $V_{CC} = 3.0\text{ V}$                                                                                                                                                     | -   | 150   | -   | MHz  |
|                |                          | $V_{CC} = 4.5\text{ V}$                                                                                                                                                     | -   | 155   | -   | MHz  |
|                |                          | $R_L = 50\text{ }\Omega$ ; $C_L = 5\text{ pF}$ ; see <a href="#">Figure 20</a>                                                                                              |     |       |     |      |
|                |                          | $V_{CC} = 1.65\text{ V}$                                                                                                                                                    | -   | > 500 | -   | MHz  |
|                |                          | $V_{CC} = 2.3\text{ V}$                                                                                                                                                     | -   | > 500 | -   | MHz  |
|                |                          | $V_{CC} = 3.0\text{ V}$                                                                                                                                                     | -   | > 500 | -   | MHz  |
|                |                          | $V_{CC} = 4.5\text{ V}$                                                                                                                                                     | -   | > 500 | -   | MHz  |
|                |                          | $R_L = 50\text{ }\Omega$ ; $C_L = 10\text{ pF}$ ; see <a href="#">Figure 20</a>                                                                                             |     |       |     |      |
|                |                          | $V_{CC} = 1.65\text{ V}$                                                                                                                                                    | -   | 200   | -   | MHz  |
|                |                          | $V_{CC} = 2.3\text{ V}$                                                                                                                                                     | -   | 350   | -   | MHz  |
|                |                          | $V_{CC} = 3.0\text{ V}$                                                                                                                                                     | -   | 410   | -   | MHz  |
|                |                          | $V_{CC} = 4.5\text{ V}$                                                                                                                                                     | -   | 440   | -   | MHz  |
| $\alpha_{iso}$ | isolation (OFF-state)    | $R_L = 600\text{ }\Omega$ ; $C_L = 50\text{ pF}$ ; $f_i = 1\text{ MHz}$ ;<br>see <a href="#">Figure 21</a>                                                                  |     |       |     |      |
|                |                          | $V_{CC} = 1.65\text{ V}$                                                                                                                                                    | -   | -46   | -   | dB   |
|                |                          | $V_{CC} = 2.3\text{ V}$                                                                                                                                                     | -   | -46   | -   | dB   |
|                |                          | $V_{CC} = 3.0\text{ V}$                                                                                                                                                     | -   | -46   | -   | dB   |
|                |                          | $V_{CC} = 4.5\text{ V}$                                                                                                                                                     | -   | -46   | -   | dB   |
|                |                          | $R_L = 50\text{ }\Omega$ ; $C_L = 5\text{ pF}$ ; $f_i = 1\text{ MHz}$ ;<br>see <a href="#">Figure 21</a>                                                                    |     |       |     |      |
|                |                          | $V_{CC} = 1.65\text{ V}$                                                                                                                                                    | -   | -37   | -   | dB   |
|                |                          | $V_{CC} = 2.3\text{ V}$                                                                                                                                                     | -   | -37   | -   | dB   |
|                |                          | $V_{CC} = 3.0\text{ V}$                                                                                                                                                     | -   | -37   | -   | dB   |
|                |                          | $V_{CC} = 4.5\text{ V}$                                                                                                                                                     | -   | -37   | -   | dB   |
| $V_{ct}$       | crosstalk voltage        | between digital input and switch;<br>$R_L = 600\text{ }\Omega$ ; $C_L = 50\text{ pF}$ ; $f_i = 1\text{ MHz}$ ;<br>$t_r = t_f = 2\text{ ns}$ ; see <a href="#">Figure 22</a> |     |       |     |      |
|                |                          | $V_{CC} = 1.65\text{ V}$                                                                                                                                                    | -   | 69    | -   | mV   |
|                |                          | $V_{CC} = 2.3\text{ V}$                                                                                                                                                     | -   | 87    | -   | mV   |
|                |                          | $V_{CC} = 3.0\text{ V}$                                                                                                                                                     | -   | 156   | -   | mV   |
|                |                          | $V_{CC} = 4.5\text{ V}$                                                                                                                                                     | -   | 302   | -   | mV   |

**Table 12. Additional dynamic characteristics ...continued**  
At recommended operating conditions; voltages are referenced to GND (ground = 0 V);  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .

| Symbol    | Parameter        | Conditions                                                                                                                                                        | Min | Typ | Max | Unit |
|-----------|------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----|-----|-----|------|
| $Q_{inj}$ | charge injection | $C_L = 0.1\text{ nF}$ ; $V_{gen} = 0\text{ V}$ ; $R_{gen} = 0\text{ }\Omega$ ;<br>$f_i = 1\text{ MHz}$ ; $R_L = 1\text{ M}\Omega$ ; see <a href="#">Figure 23</a> |     |     |     |      |
|           |                  | $V_{CC} = 1.8\text{ V}$                                                                                                                                           | -   | 3.3 | -   | pC   |
|           |                  | $V_{CC} = 2.5\text{ V}$                                                                                                                                           | -   | 4.1 | -   | pC   |
|           |                  | $V_{CC} = 3.3\text{ V}$                                                                                                                                           | -   | 5.0 | -   | pC   |
|           |                  | $V_{CC} = 4.5\text{ V}$                                                                                                                                           | -   | 6.4 | -   | pC   |
|           |                  | $V_{CC} = 5.5\text{ V}$                                                                                                                                           | -   | 7.5 | -   | pC   |

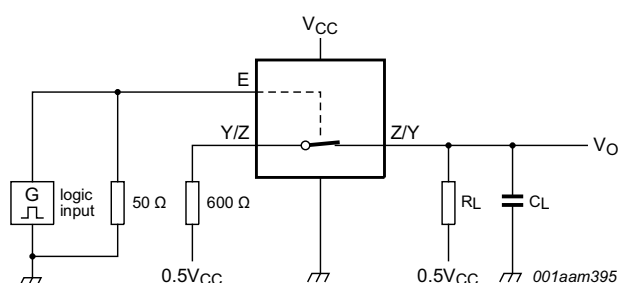
11.3 Test circuits



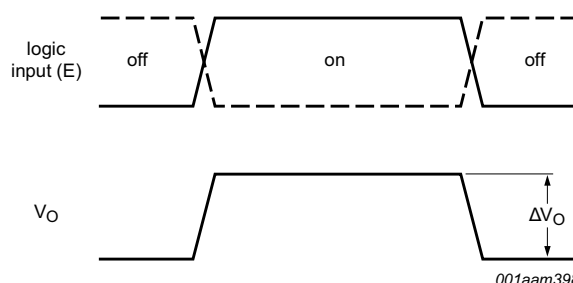
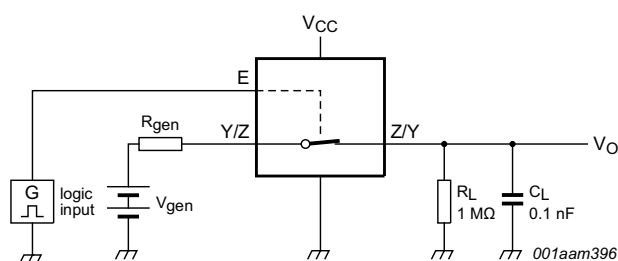


Adjust  $f_i$  voltage to obtain 0 dBm level at input.

**Fig 21. Test circuit for measuring isolation (OFF-state)**



**Fig 22. Test circuit for measuring crosstalk between digital input and switch**



$$Q_{inj} = \Delta V_O \times C_L$$

$\Delta V_O$  = output voltage variation.

$R_{gen}$  = generator resistance.

$V_{gen}$  = generator voltage.

**Fig 23. Test circuit for measuring charge injection**

12. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1

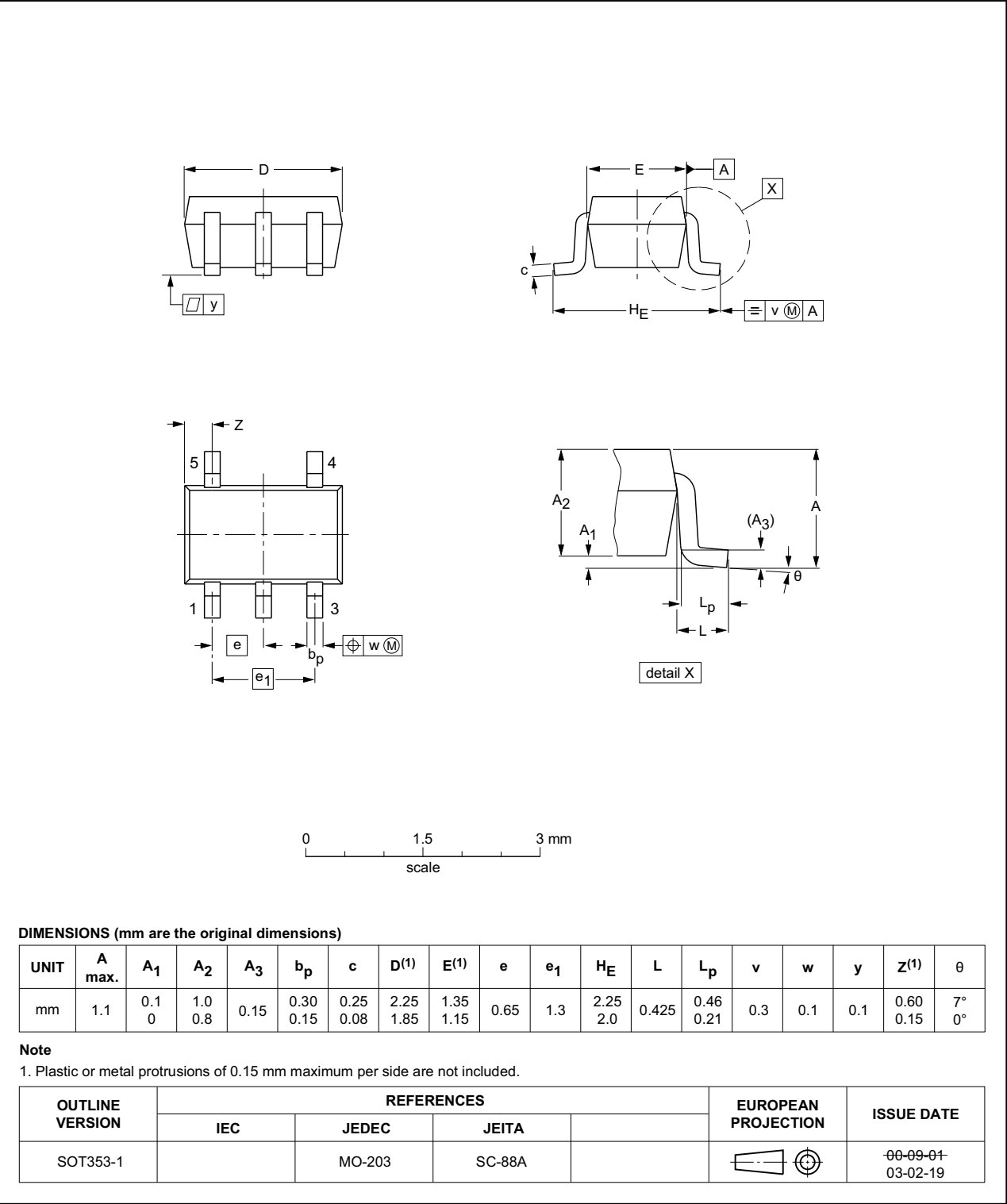


Fig 24. Package outline SOT353-1 (TSSOP5)

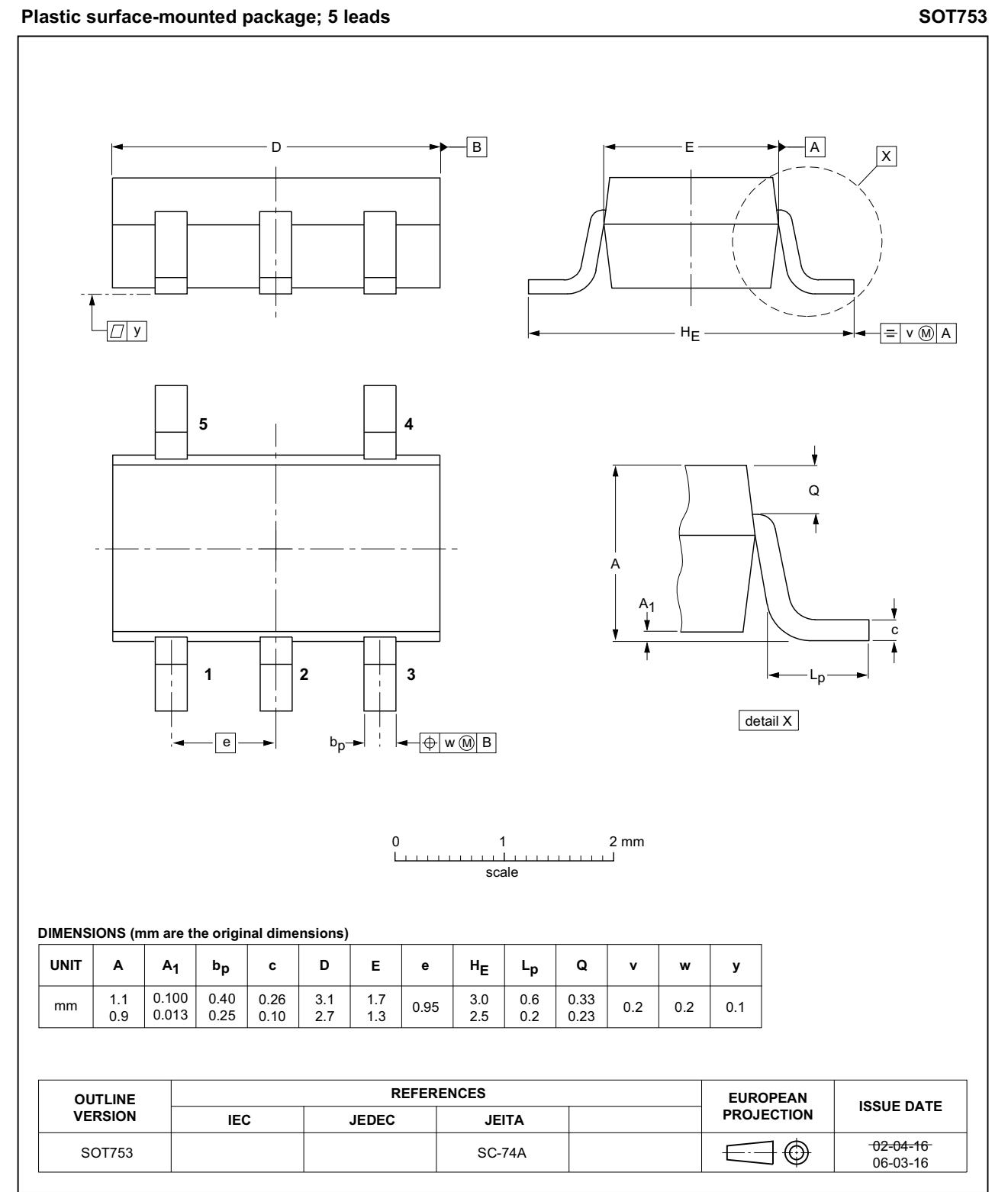


Fig 25. Package outline SOT753 (SC-74A)

74LVC1G66

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XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1 x 0.5 mm

SOT891

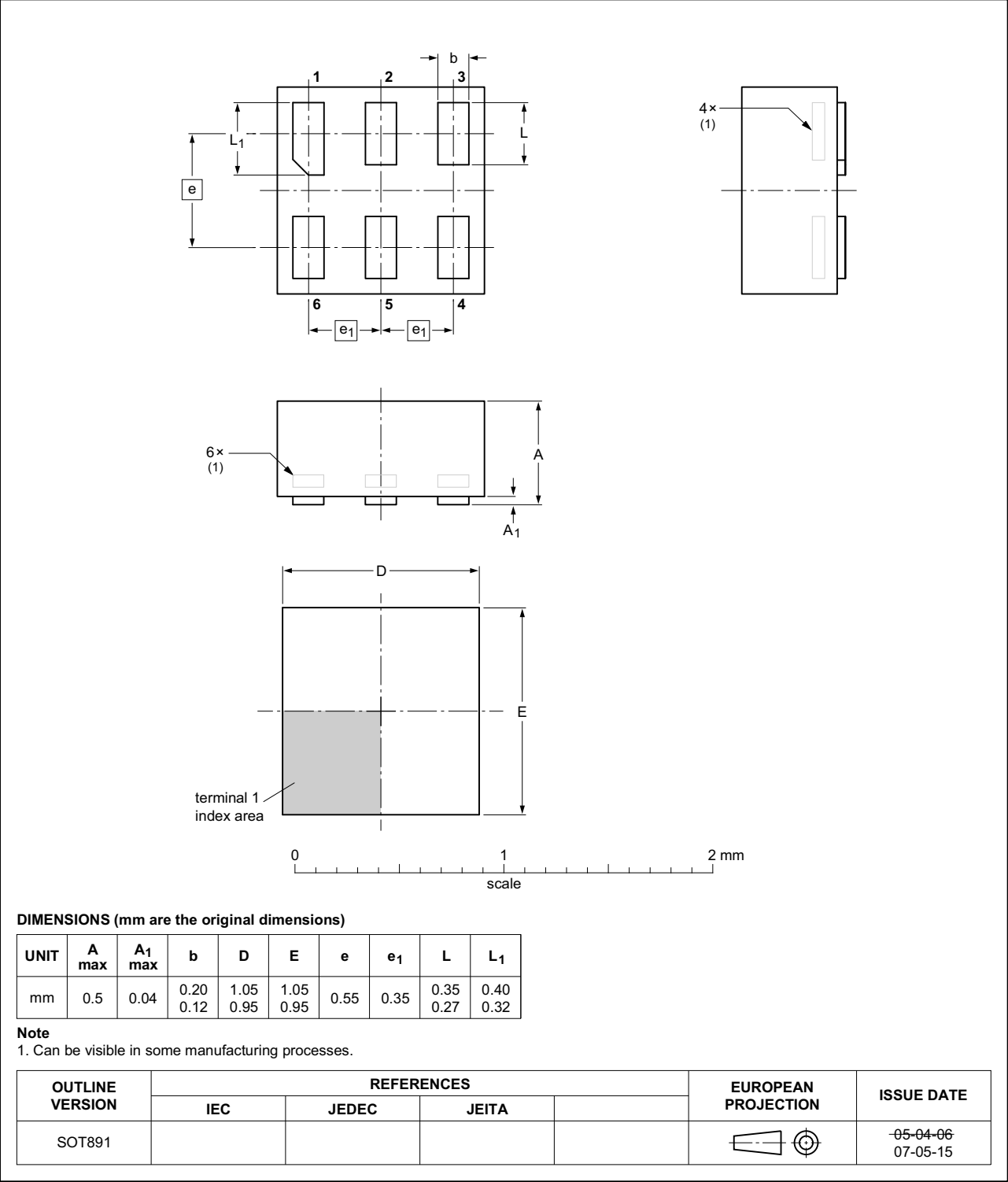


Fig 27. Package outline SOT891 (XSON6)

XSON6: extremely thin small outline package; no leads;  
6 terminals; body 0.9 x 1.0 x 0.35 mm

SOT1115

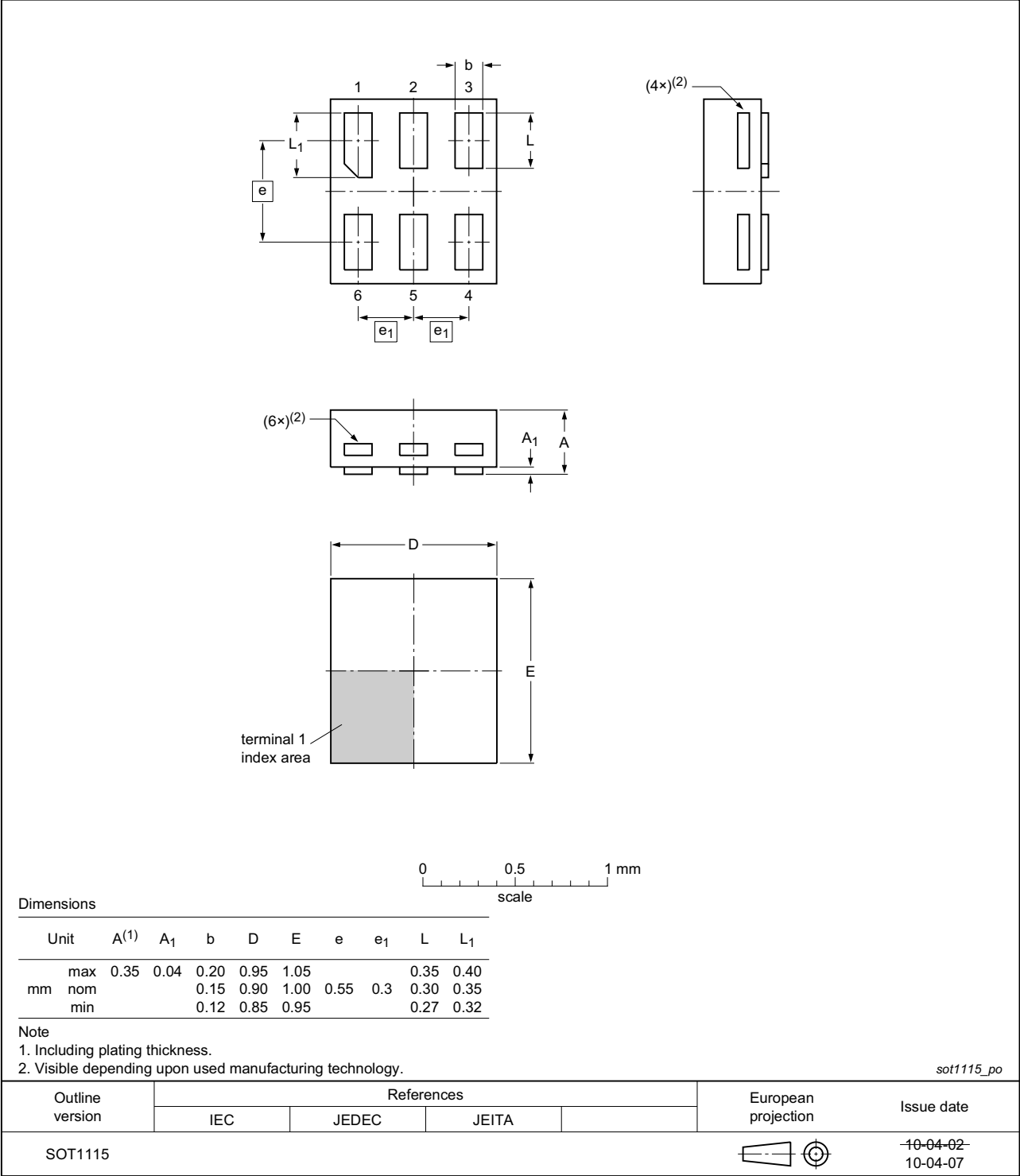


Fig 28. Package outline SOT1115 (XSON6)

**XSON6: extremely thin small outline package; no leads;**  
**6 terminals; body 1.0 x 1.0 x 0.35 mm**

SOT1202

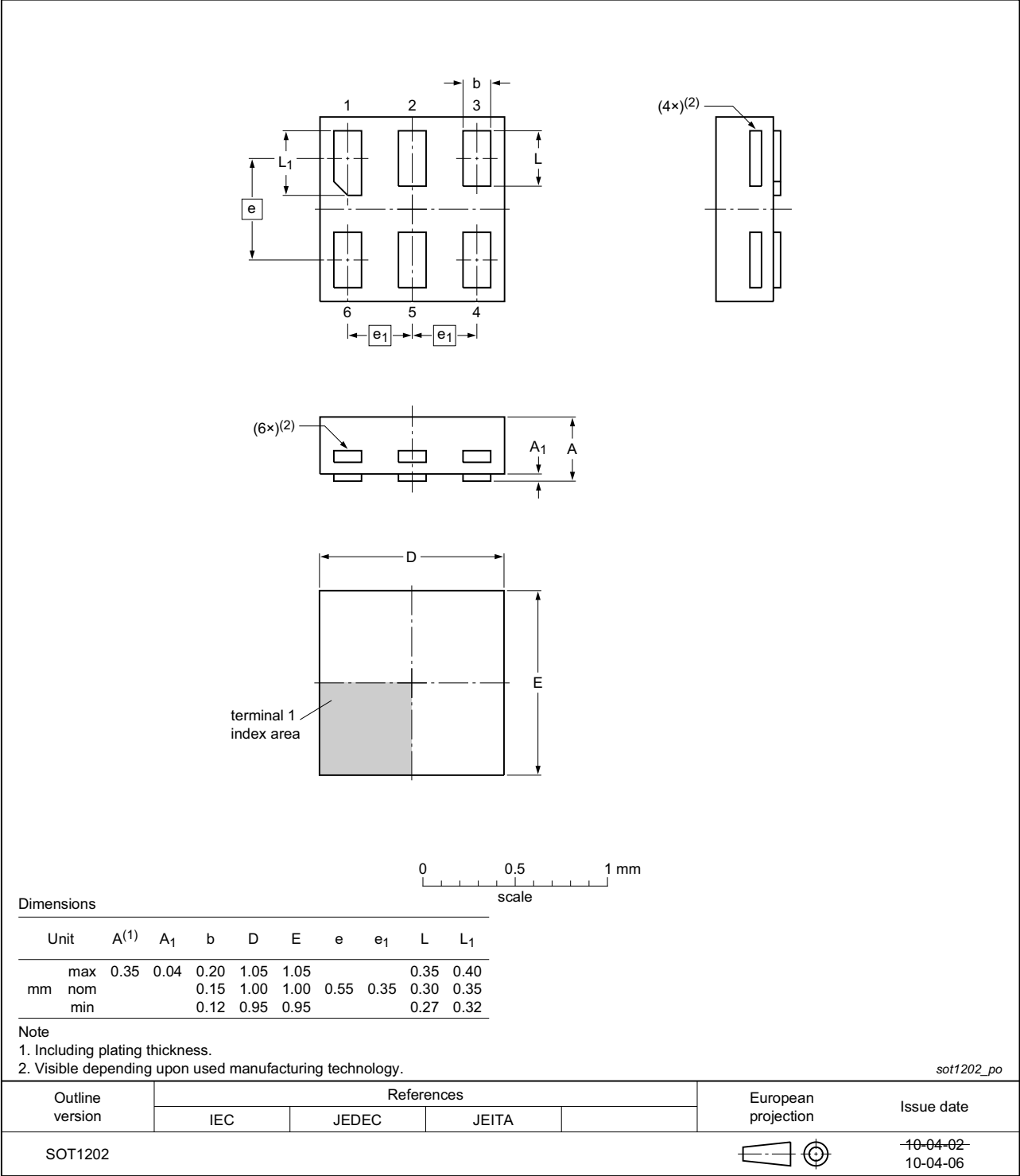


Fig 29. Package outline SOT1202 (XSON6)

## 13. Abbreviations

Table 13. Abbreviations

| Acronym | Description                             |
|---------|-----------------------------------------|
| CMOS    | Complementary Metal Oxide Semiconductor |
| TTL     | Transistor-Transistor Logic             |
| HBM     | Human Body Model                        |
| ESD     | ElectroStatic Discharge                 |
| MM      | Machine Model                           |
| DUT     | Device Under Test                       |

## 14. Revision history

Table 14. Revision history

| Document ID    | Release date                                       | Data sheet status     | Change notice | Supersedes    |
|----------------|----------------------------------------------------|-----------------------|---------------|---------------|
| 74LVC1G66 v.9  | 20150115                                           | Product data sheet    | -             | 74LVC1G66 v.8 |
| Modifications: | • SOT886 (XSON6) package outline drawing modified. |                       |               |               |
| 74LVC1G66 v.8  | 20111202                                           | Product data sheet    | -             | 74LVC1G66 v.7 |
| Modifications: | • Legal pages updated.                             |                       |               |               |
| 74LVC1G66 v.7  | 20100730                                           | Product data sheet    | -             | 74LVC1G66 v.6 |
| 74LVC1G66 v.6  | 20070827                                           | Product data sheet    | -             | 74LVC1G66 v.5 |
| 74LVC1G66 v.5  | 20070807                                           | Product data sheet    | -             | 74LVC1G66 v.4 |
| 74LVC1G66 v.4  | 20040413                                           | Product specification | -             | 74LVC1G66 v.3 |
| 74LVC1G66 v.3  | 20021115                                           | Product specification | -             | 74LVC1G66 v.2 |
| 74LVC1G66 v.2  | 20020529                                           | Product specification | -             | 74LVC1G66 v.1 |
| 74LVC1G66 v.1  | 20011030                                           | Product specification | -             | -             |

## 15. Legal information

### 15.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition                                                                            |
|-----------------------------------|-------------------------------|---------------------------------------------------------------------------------------|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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Date of release: 15 January 2015

Document identifier: 74LVC1G66

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